I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231, on October 10, 2003. The applicant and/or cattorney requests the date of deposit as the filing date. Depositor: Karen Cinq-Mars

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

October 10, 2003

Chen, et al.

**Group Art Unit:** 

Serial No. 10/605,134 :

Examiner:

Filed: 9/10/03

**International Business Machines Corporation** 

2070 Route 52

Hopewell Junction, NY 12533

TITLE:

STRUCTURE AND METHOD OF MAKING STRAINED CHANNEL CMOS TRANSISTORS HAVING LATTICE-MISMATCHED EPITAXIAL EXTENSION AND SOURCE AND DRAIN

**REGIONS** 

## INFORMATION DISCLOSURE STATEMENT

**Commissioner for Patents** P.O. Box 1450 Alexandria, VA 22313-1450

Sir.

Pursuant to the duty of disclosure set forth in 37 C.F.R. 1.56, and further pursuant to the provisions of 37 C.F.R. 1.97 and 1.98, applicants hereby respectfully submit copies of the non-US patents and publications as listed on Form PTO-1449, attached hereto.

In citing these documents, no representation is made nor intended as to the pertinency or nonpertinency of the art, that better art than that listed is not available, or that other art is not applicable.

No fee is believed to be due for this submission. If any fees are required, however, the Commissioner is hereby authorized to charge such fees to Deposit Account No. 09-0458.

Respectfully submitted,

Chen, et al.

H. Daniel Sethnurmann Registration No. 35,791

Telephone No. 845-894-2481

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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance <u>and</u> not considered. Include copy of this form with next communication to applicant.